

View Online at <https://aerobasegroup.com/nsn/5961-00-137-7204>

Inclosure Material:

Ceramic

Overall Length:

0.260 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.370 inches

Component Name And Quantity:

4 transistor

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

40.0 collector to emitter voltage/static/base open all transistor and 65.0 collector to base voltage, dc all transistor and 6.0 emitter to base voltage, dc all transistor

Current Rating Per Characteristic:

1.00 amperes source cutoff current all transistor

Power Rating Per Characteristic:

600.0 milliwatts small-signal input power, common-collector preset all transistor

Transfer Ratio:

150.0 static forward current transfer ratio, common-emitter all transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

All transistor junction pattern arrangement: npn

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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